



MMST3904

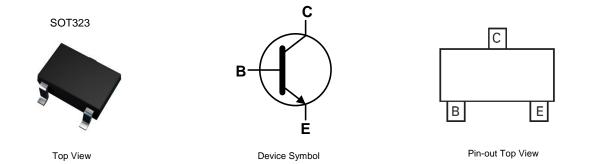
40V NPN SMALL SIGNAL TRANSISTOR IN SOT323

Features

- BV_{CEO} > 40V
- I_C = 200mA Collector Current
- Epitaxial Planar Die Construction
- Ultra-Small Surface Mount Package
- Complementary PNP Type: MMST3906
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT323
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 3
- Weight: 0.006 grams (Approximate)



Ordering Information (Notes 4 & 5)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
MMST3904-7-F	AEC-Q101	K2N	7	8	3,000
MMST3904Q-7-F	Automotive	K2N	7	8	3,000

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

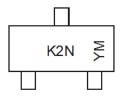
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to https://www.diodes.com/quality/.

5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Notes:



 $\begin{array}{l} {\sf K2N} = {\sf Product Type Marking Code} \\ {\sf YM} = {\sf Date Code Marking} \\ {\sf Y or } \overline{{\sf Y}} = {\sf Year (ex: F=2018)} \\ {\sf M or } \overline{{\sf M}} = {\sf Month (ex: 9=September)} \end{array}$

Date Code	Key													
Year	201	8	20	019	2020	2021	2022	2023	2024	4 20	25 2	2026	2027	2028
Code	F			G	Н		J	K	L	Ν	Λ	Ν	0	Р
Mont	h	Ja	n	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	;	1		2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	60	V
Collector-Emitter Voltage	V _{CEO}	40	V
Emitter-Base Voltage	V _{EBO}	6	V
Collector Current	lc	200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	PD	200	mW
Thermal Resistance, Junction to Ambient (Note 6)	R _{0JA}	625	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

ESD Ratings (Note 7)

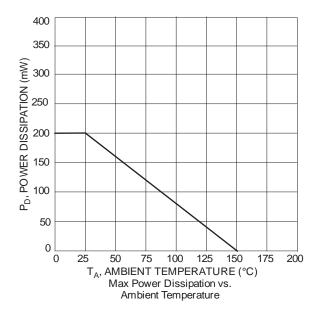
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Notes: 6. For a device mounted with the collector lead on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.

7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





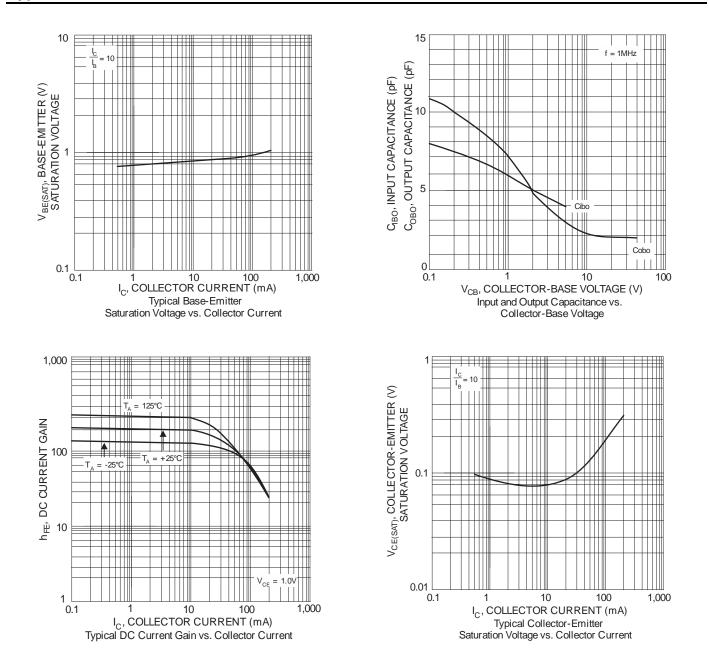
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)					
Collector-Base Breakdown Voltage	BV _{CBO}	60		V	$I_{\rm C} = 10\mu A, I_{\rm E} = 0$
Collector-Emitter Breakdown Voltage	BV _{CEO}	40		V	$I_{\rm C} = 1 {\rm mA}, I_{\rm B} = 0$
Emitter-Base Breakdown Voltage	BV _{EBO}	5		V	$I_{\rm E} = 10\mu A, I_{\rm C} = 0$
Collector Cutoff Current	I _{CEX}		50	nA	$V_{CE} = 30V, V_{EB(OFF)} = 3V$
Base Cutoff Current	I _{BL}		50	nA	$V_{CE} = 30V, V_{EB(OFF)} = 3V$
ON CHARACTERISTICS (Note 8)					
		40			$I_{C} = 100 \mu A, V_{CE} = 1 V$
		70			$I_C = 1mA$, $V_{CE} = 1V$
DC Current Gain	h _{FE}	100	300		$I_{C} = 10 \text{mA}, V_{CE} = 1 \text{V}$
		60	_		$I_{C} = 50 \text{mA}, V_{CE} = 1 \text{V}$
		30			$I_{C} = 100 \text{mA}, V_{CE} = 1 \text{V}$
Collector-Emitter Saturation Voltage	M	-	0.25	V	$I_{C} = 10mA, I_{B} = 1mA$
Collector-Emitter Saturation voltage	V _{CE(SAT)}		0.30	v	$I_{C} = 50 \text{mA}, I_{B} = 5 \text{mA}$
Base-Emitter Saturation Voltage	\/	0.65	0.85	V	$I_{C} = 10mA, I_{B} = 1mA$
5	V _{BE(SAT)}		0.95	v	$I_{C} = 50 \text{mA}, I_{B} = 5 \text{mA}$
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	C _{obo}	_	4	pF	$V_{CB} = 5V, f = 1.0MHz, I_E = 0$
Input Capacitance	Cibo	_	8	pF	$V_{EB} = 0.5V, f = 1.0MHz, I_{C} = 0$
Input Impedance	h _{ie}	1	10	kΩ	
Voltage Feedback Ratio	h _{re}	0.5	8.0	x 10 ⁻⁴	$V_{CE} = 10V, I_{C} = 1mA,$
Small Signal Current Gain	h _{fe}	100	400		f = 1.0MHz
Output Admittance	h _{oe}	1	40	μS	
Current Gain-Bandwidth Product	f _T	300		MHz	$V_{CE} = 20V, I_C = 10mA,$ f = 100MHz
Noise Figure	NF		5	dB	$V_{CC} = 5V, I_C = 100\mu A,$
-					$R_{S} = 1k\Omega, f = 1MHz$
			25		
Delay Time	t _D		35	ns	$V_{CC} = 3V, I_C = 10mA,$
Rise Time	t _R		35	ns	$V_{BE(OFF)} = -0.5V, I_{B1} = 1mA$

Notes: 8. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

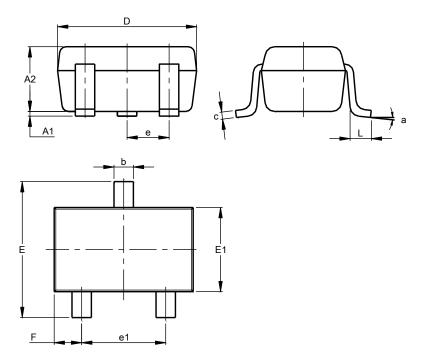




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

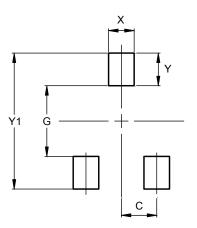
SOT323



SOT323								
Dim	Min	Max	Тур					
A1	0.00	0.10	0.05					
A2	0.90	1.00	0.95					
b	0.25	0.40	0.30					
c	0.10	0.18	0.11					
D	1.80	2.20	2.15					
Е	2.00	2.20	2.10					
E1	1.15	1.35	1.30					
е	C).650 B	SC					
e1	1.20	1.40	1.30					
F	0.375	0.475	0.425					
L	0.25	0.40	0.30					
а	0°	8°						
All	Dimen	sions i	in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT323

Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.470
Y	0.600
Y1	2.500



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